, ,	L	Hits	Search Text	DB	Time stamp
_	Number				
	1	7654	((438/637) or (438/639) or (438/640) or (438/641) or (438/666) or (438/669) or (438/671) or (438/672) or (438/762) or (438/765) or (438/770) or (438/771) or (438/772) or (438/774) or (438/787) or (438/986) or (438/947) or (438/948) or (438/949) or (438/950)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/24 19:30
:	2	859		USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/24 20:13
4	4	0	((((438/637) or (438/639) or (438/640) or (438/641) or (438/666) or (438/669) or (438/671) or (438/672) or (438/762) or (438/765) or (438/770) or (438/771) or (438/772) or (438/774) or (438/772) or (438/774) or (438/787) or (438/987) or (438/987) or (438/988) or (438/999) or (438/988) or (438/999) or (438/998)).CCLS.) and (photoresist near10 (si or silicon or sylyated or silated))) and transistor and gate and (source or drain)) and ((bilayer or (bi adj2 layer)) near5 resist)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/24 19:35
	5	0		USPAT;	2004/07/24
			or (438/641) or (438/666) or (438/669) or (438/671) or (438/672) or (438/762) or (438/765) or (438/770) or (438/771) or (438/772) or (438/774) or (438/782) or (438/787) or (438/984) or (438/984) or (438/984) or (438/984) or (438/9850)).CCLS.) and (photoresist near10 (si or silicon or sylvated or silated))) and transistor and gate and (source or drain)) and ((bilayer or (bi adj2 layer)) near10 resist)	US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	19:36
	6	1	(((((438/637) or (438/639) or (438/640) or (438/641) or (438/666) or (438/669) or (438/671) or (438/672) or (438/762) or (438/765) or (438/770) or (438/771) or (438/772) or (438/774) or (438/787) or (438/906) or (438/947) or (438/948) or (438/949) or (438/950)).CCLS.) and (photoresist near10 (si or silicon or sylyated or silated))) and transistor and gate and (source or drain)) and ((bilayer or (bi adj2 layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/24 19:36
	3	319	near10 photoresist) ((((438/637) or (438/639) or (438/640) or (438/641) or (438/666) or (438/669) or (438/671) or (438/672) or (438/762) or (438/765) or (438/770) or (438/771) or (438/772) or (438/774) or (438/782) or (438/787) or (438/906) or (438/947) or (438/948) or (438/949) or (438/950)).CCLS.) and (photoresist near10 (si or silicon or sylyated or silated))) and transistor and gate and (source or drain)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/07/24 19:51

1		
8	or (438/641) or (438/666) or (438/669) or (438/671) or (438/672) or (438/762) or (438/765) or (438/770) or (438/771) or (438/772) or (438/774) or (438/782) or (438/787) or (438/906) or (438/947) or (438/948) or (438/949) or (438/950)).CCLS.) and (photoresist near10	2004/07/24 20:04
9	or (438/641) or (438/666) or (438/669) or (438/671) or (438/672) or (438/762) or (438/765) or (438/770) or (438/771) or (438/772) or (438/774) or (438/782) or (438/787) or (438/906) or (438/947) or	2004/07/24 19:53
10	or (438/641) or (438/666) or (438/669) or (438/671) or (438/672) or (438/762) or (438/765) or (438/770) or (438/771) or (438/772) or (438/774) or (438/782) or (438/787) or (438/906) or (438/947) or (438/948) or (438/949) or (438/950)).CCLS.) and (photoresist near10	2004/07/24 19:53
7		2004/07/24 20:13
11	drain)) and (selective\$2 near10 deposit\$3 near10 (insulat\$3 or dielectric)) 42 (438/\$.ccls. or 257/\$.ccls.) and ((self adj aligned adj contact) or (borderless adj contact)) and bitline  USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/07/24 20:08
12		2004/07/24 20:57
13	13 ((438/\$.ccls. or 257/\$.ccls.) and ((self   USPAT;	2004/07/24 20:04
14	55 (438/\$.ccls. or 257/\$.ccls.) and ((self   USPAT;   :	2004/07/24 20:12

, L				
15	13	((438/\$.ccls. or 257/\$.ccls.) and ((self	USPAT;	2004/07/24
		adj aligned adj contact) or sac or	US-PGPUB;	20:09
		(borderless adj contact)) and bitline)	EPO; JPO;	<u> </u>
		not ((438/\$.ccls. or 257/\$.ccls.) and	DERWENT;	!
		((self adj aligned adj contact) or	IBM TDB	1
		(borderless adj contact)) and bitline)	<u>-</u>	
16	2612	(438/\$.ccls. or 257/\$.ccls.) and ((self	USPAT;	2004/07/24
		adj aligned adj contact) or sac or	US-PGPUB;	20:57
		(borderless adj contact)) and (source or	EPO; JPO;	
	1	drain)	DERWENT;	
	1		IBM TDB	
17	121	((438/\$.ccls. or 257/\$.ccls.) and ((self	USPAT;	2004/07/24
1 '	121	adj aligned adj contact) or sac or	US-PGPUB;	20:57
		(borderless adj contact)) and (source or	EPO; JPO;	20.07
		drain)) and (selective\$2 near10 deposit\$3	DERWENT;	•
		near10 (insulat\$3 or dielectric))	IBM TDB	
18	24	(((438/\$.ccls. or 257/\$.ccls.) and ((self	USPAT;	2004/07/24
10	24		US-PGPUB;	20:24
		adj aligned adj contact) or sac or		20.24
		(borderless adj contact)) and (source or	EPO; JPO;	
		drain)) and (selective\$2 near10 deposit\$3	DERWENT;	1
		near10 (insulat\$3 or dielectric))) and	IBM_TDB	
		(photoresist near10 (si or silicon or		[
1.0	1.4	sylvated or silated))	IICDAM.	2004/07/24
19	14		USPAT;	2004/07/24
		("5565376") or ("5583358") or ("5696036")	US-PGPUB;	20:56
		or ("5872041")).PN.	EPO; JPO;	
}			DERWENT;	
			IBM_TDB	
20	329	((438/256) or (438/399)).CCLS.	USPAT;	2004/07/24
			US-PGPUB;	20:56
			EPO; JPO;	
			DERWENT;	
		(400/000)	-I-BM-TDB-	2004/07/04
	0	((((438/256) or (438/399)).CCLS.) and	USPAT;	2004/07/24
		((self adj aligned adj contact) or sac or	US-PGPUB;	20:57
]	ŀ	(borderless adj contact)) and (source or	EPO; JPO;	
		drain)) and (selective\$2 near10 deposit\$3	DERWENT;	
		near10 (insulat\$3 or dielectric))	IBM_TDB	0004/07/04
23	0	1 , , , , , = = ,	USPAT;	2004/07/24
		((self adj aligned adj contact) or sac or	US-PGPUB;	20:57
1		(borderless adj contact)) and (source or	EPO; JPO;	
		drain)) and (selective\$2 near10 deposit\$3	DERWENT;	1
1		near10 (insulat\$3 or dielectric))) and	IBM_TDB	
		(liquid adj phase adj oxide)		
24	0	((((438/256) or (438/399)).CCLS.) and	USPAT;	2004/07/24
		((self adj aligned adj contact) or sac or	US-PGPUB;	20:58
1		(borderless adj contact)) and (source or	EPO; JPO;	
		drain)) and (liquid adj phase adj oxide)	DERWENT;	
1			IBM_TDB	
21	41	1 , , ,	USPAT;	2004/07/24
		((self adj aligned adj contact) or sac or	US-PGPUB;	20:58
		(borderless adj contact)) and (source or	EPO; JPO;	
	1	drain)	DERWENT;	
			IBM_TDB	
	•			